
2SJ350

Silicon P-Channel MOS FET

HITACHI

ADE-208-138
1st. Edition

Application

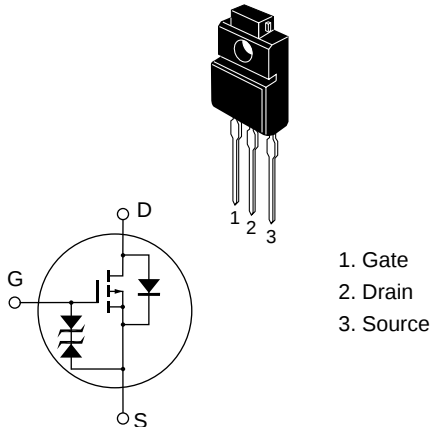
High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- 4 V gate drive device can be driven from 5 V source
- Suitable for switching regulator, DC-DC converter

Outline

TO-220FM



Absolute Maximum Ratings (Ta = 25°C)

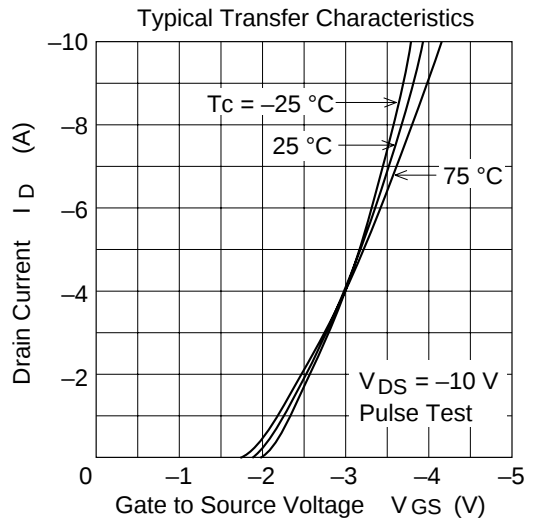
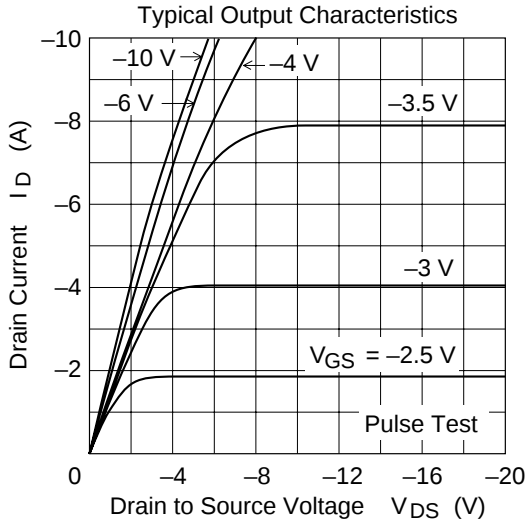
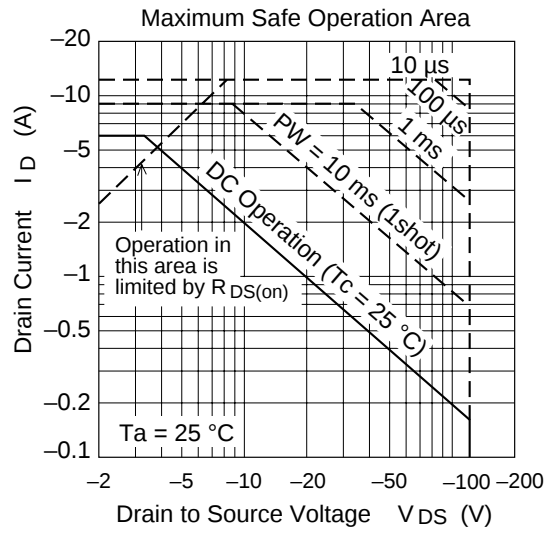
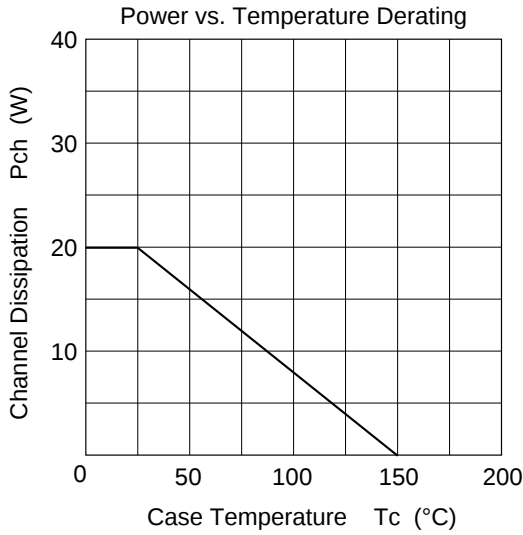
Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	-120	V
Gate to source voltage	V_{GSS}	±20	V
Drain current	I_D	-6	A
Drain peak current	$I_{D(pulse)}^{*1}$	-12	A
Body to drain diode reverse drain current	I_{DR}	-6	A
Channel dissipation	Pch^{*2}	20	W
Channel temperature	T_{ch}	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

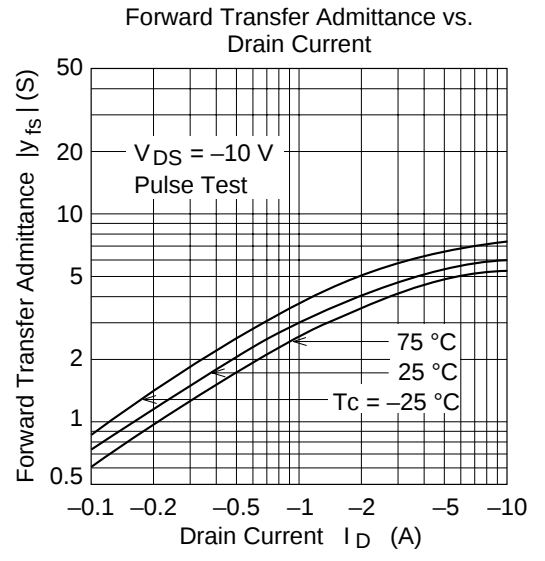
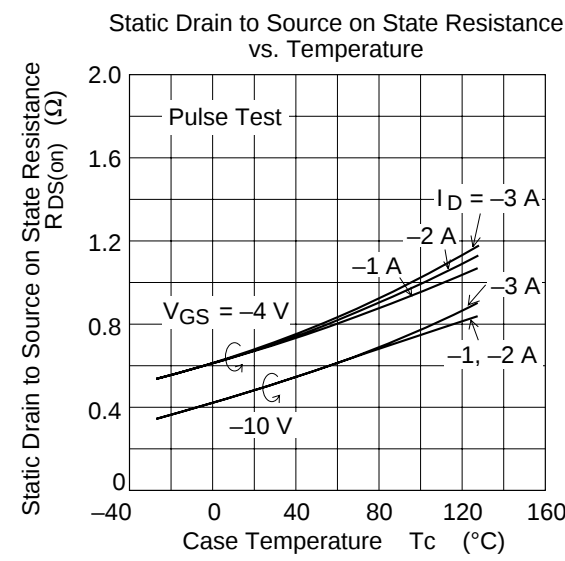
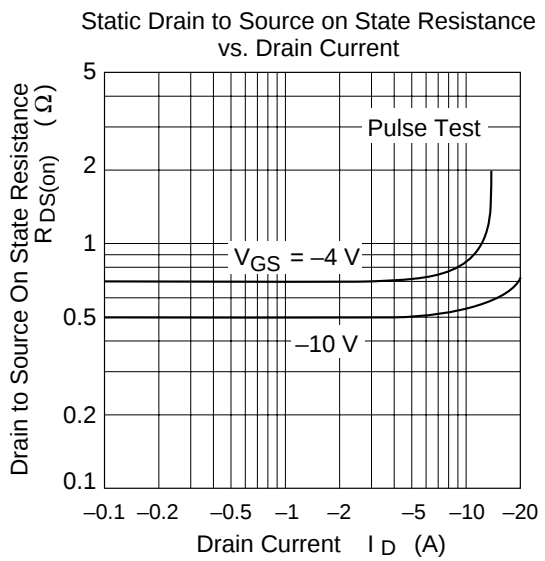
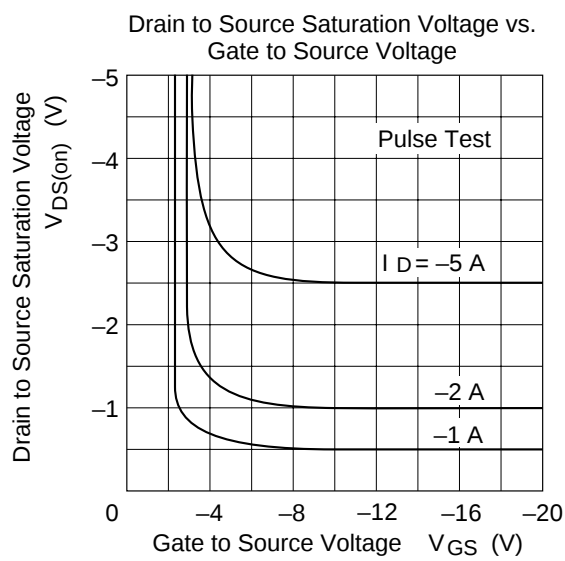
Notes: 1. $PW \leq 10 \mu s$, duty cycle $\leq 1\%$
2. Value at $T_c = 25^\circ C$

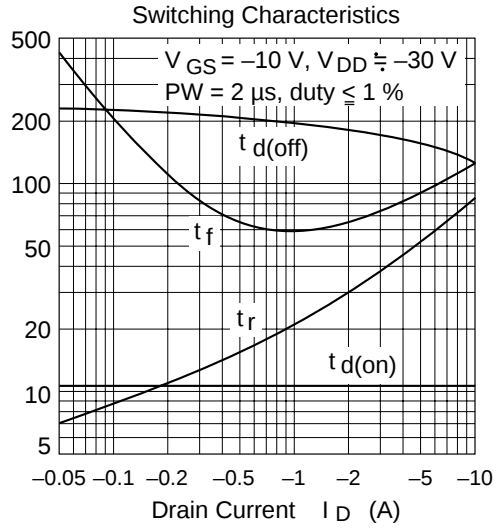
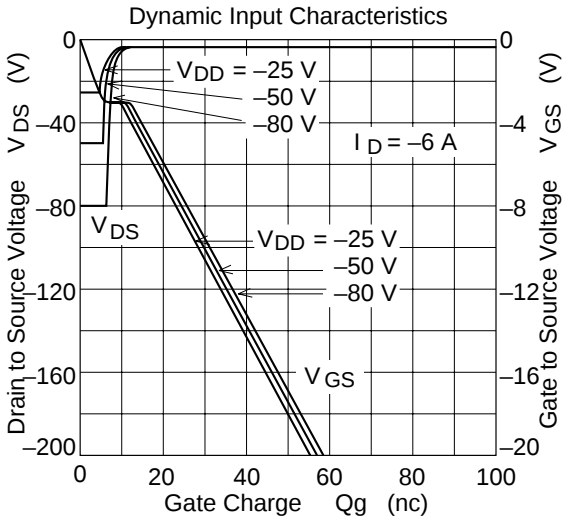
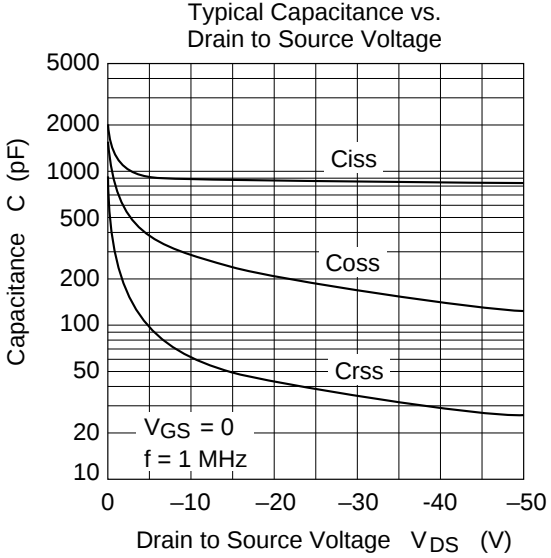
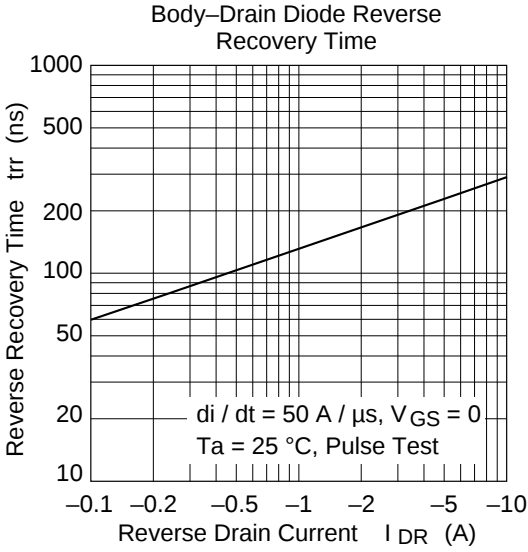
Electrical Characteristics (Ta = 25°C)

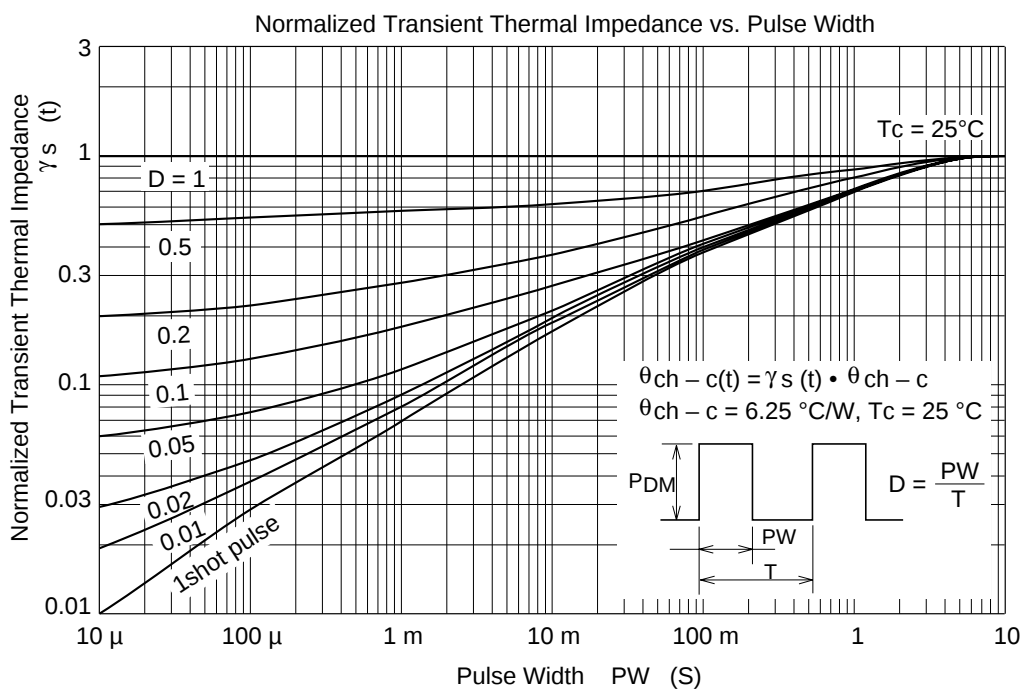
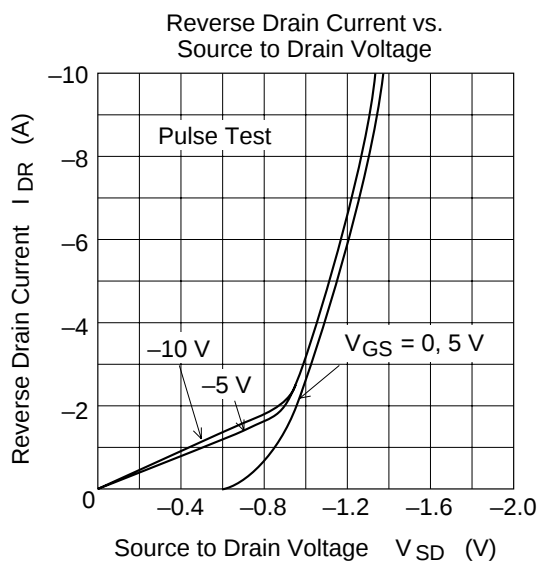
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	-120	—	—	V	$I_D = -10 \text{ mA}$, $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	—	—	V	$I_G = \pm 100 \mu A$, $V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	±10	μA	$V_{GS} = \pm 16 \text{ V}$, $V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	-250	μA	$V_{DS} = -100 \text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-1.0	—	-2.0	V	$I_D = -1 \text{ mA}$, $V_{DS} = -10 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)}$	—	0.5	0.7	Ω	$I_D = -4 \text{ A}$, $V_{GS} = -10 \text{ V}^{*1}$
		—	0.7	0.9	Ω	$I_D = -4 \text{ A}$, $V_{GS} = -4 \text{ V}^{*1}$
Forward transfer admittance	$ y_{fs} $	3.0	5.0	—	S	$I_D = -4 \text{ A}$, $V_{DS} = -10 \text{ V}^{*1}$
Input capacitance	C_{iss}	—	900	—	pF	$V_{DS} = -10 \text{ V}$, $V_{GS} = 0$, $f = 1 \text{ MHz}$
Output capacitance	C_{oss}	—	265	—	pF	
Reverse transfer capacitance	C_{rss}	—	65	—	pF	
Turn-on delay time	$t_{d(on)}$	—	11	—	ns	$I_D = -4 \text{ A}$, $V_{GS} = -10 \text{ V}$, $R_L = 7.5 \Omega$
Rise time	t_r	—	45	—	ns	
Turn-off delay time	$t_{d(off)}$	—	170	—	ns	
Fall time	t_f	—	80	—	ns	
Body to drain diode forward voltage	V_{DF}	—	-1.2	—	V	$I_F = -6 \text{ A}$, $V_{GS} = 0$
Body to drain diode reverse recovery time	t_{rr}	—	240	—	ns	$I_F = -6 \text{ A}$, $V_{GS} = 0$, $di_F/dt = 50 \text{ A}/\mu s$

Note: 1. Pulse test

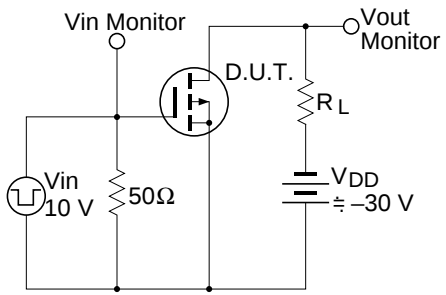




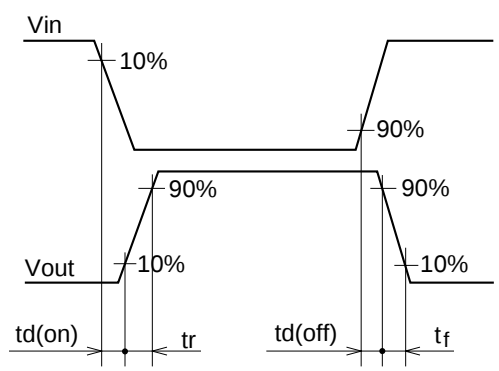




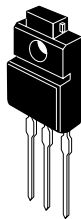
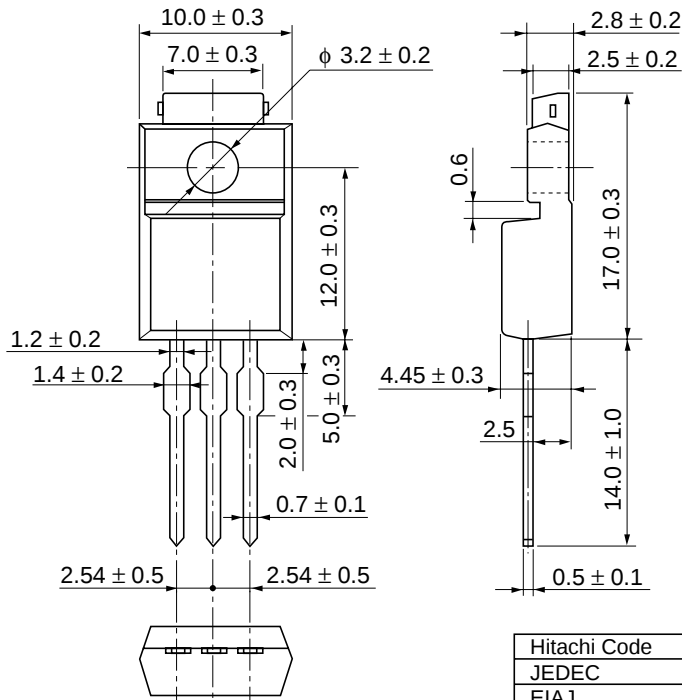
Switching Time Test Circuit



Waveforms



Unit: mm



Hitachi Code	TO-220FM
JEDEC	—
EIAJ	Conforms
Weight (reference value)	1.8 g

Cautions

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